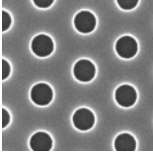
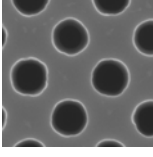
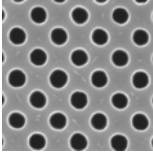
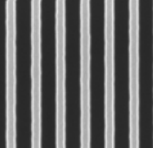

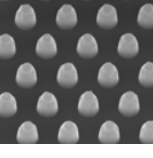
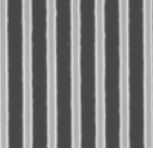
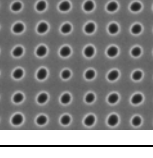
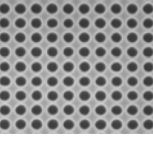
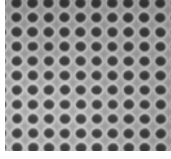
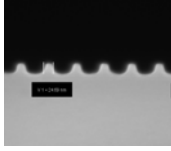
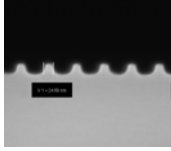



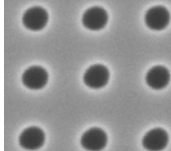
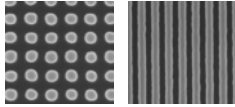


ID	Description	Image	Remarks	Price (USD)
NSSP 01	Hexagonal array Period = 600 nm Hole diameter = ~ 300 nm Height = 50 nm or 340 nm Area: 20 x 20 mm ² Chip size: 20 x 20 mm ²		Two different heights available 50 nm or 340 nm	950
NSSP 02	Square array Period = 350 nm Hole diameter = 220 – 260 nm Height = 320 nm Area: 20 x 20 mm ²		Varying hole diameter 220 – 260 nm	1'450
NSSP 03	Square array Period = 350 nm Hole diameter = 230 nm Height = 325 nm Area = 20 x 20 mm ²		Occasional isolated defects	1'450
NSSP 04	Line grating Period = 300,400,500,600 nm Height = 330 nm Area: each period 10 x 10 mm ²		Isolated ~ 1 mm defect	1'400
NSSP 05	Line grating Period = 300,400,500,600 nm Height = 230 nm Area: each period 10 x 10 mm ²		Isolated ~ 1 mm defect	1'400
NSSP 06	Hexagonal pillar array Period = 600 nm Pillar diameter = 310 nm Height = 330 nm Area: 46 x 46 mm ²		Large area Conical tops	1'900
NSSP 07	Line grating Period = 300,400,500,600nm Height = 325nm Area: each period 10 x 10 mm ²		Occasional isolated defects 5 um – 10 um	1'400
NSSE 01	Large area nanohole array Period = 60 nm Hole diameter = 30 nm Area: 10 x 10 mm ²		Occasional closed holes (<1%)	3'350
NSSX 01	Nanohole array Period = 90/100 nm Height = 62 nm Area: 25x 0.6 x 0.6 mm ² Chip size: 20 x 20 mm ²		Custom production	1'700

ID	Description	Image	Remarks	Price (USD)
NSSX 02	Nanohole array Period = 90/100 nm Height = 62 nm Area: 4x 0.6 x 0.6 mm ² Chip size: 15 x 15 mm ²		Large holes	950
NSSX 03	Large area linear grating Period = 70 nm Height = 32 nm Area: 21x 0.5 x 1.2 mm ² Chip size 10 x 10 mm ²		Large area!	2'850
NSSX 04	Line grating Period = 70 nm Height = 32 nm Area: 4x 0.5 x 1.2 mm ² Chip size 20 x 20 mm ²		Shallow grating 32 nm	1'100
NSSX 05	High-resolution nanodot array Period = 35 nm and 42 nm Dot diameter: 15 - 20 nm Height= 25 - 30 nm Area: >25x25 um ² each period			950
NSSX 06	Line grating Period = 70 nm Height = 40 nm Area: 4x 0.5 x 1.2 mm ² Chip size 20 x 20 mm ²		Shallow grating 40 nm	1'300
NSSE 02	Nanopillar array Period = 200 nm Pillar diameter = 45 nm Pillar height = 75 nm Area= 10 x 10 mm ²		Missing pillars <1%	2'750
NSSE 03	Nanohole array Hole diameter: 45 nm Period = 90 nm Height = 50 nm Area: 4x 0.6 x 0.6 mm ² Chip size: 15 x 15 mm ²		Shallow grating 50 nm	1'100
NSSE 04	Nanohole & line/space array Period = 100 nm Height = 50 nm Area: 0.5 x 0.5 mm ² each Chip size: 20 x 20 mm ²			850

All structures are etched in Si. Limited-period offer. Prices valid until supplies last. Anti-adhesion coating can be applied to all structures for an additional price. All products in this offer ship within three days of order. Prices do not include shipping charges.